

COMPLEMENTARY SILICON DARLINGTON POWER TRANSISTORS



Central Semiconductor Corp.

www.centralsemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR 2N6298 series devices are complementary silicon Darlington power transistors manufactured by the epitaxial base process designed for high gain amplifier and medium speed switching applications.

MAX

UNITS

MARKING: FULL PART NUMBER

		2N6298	2N6299	
MAXIMUM RATINGS: (T _C =25°C)	SYMBOL	<u>2N6300</u>	<u>2N6301</u>	UNITS
Collector-Base Voltage	VCBO	60	80	V
Collector-Emitter Voltage	V _{CEO}	60	80	V
Emitter-Base Voltage	V _{EBO}	5.0		V
Continuous Collector Current	IC	8	.0	А
Peak Collector Current	ICM	1	6	А
Continuous Base Current	۱ _B	12	20	mA
Power Dissipation	PD	75		W
Operating and Storage Junction Temperature	TJ, T _{stg}	-65 to	+200	°C
Thermal Resistance	ΘJC	2.	33	°C/W

 ELECTRICAL
 CHARACTERISTICS: (T_C=25°C unless otherwise noted)

 SYMBOL
 TEST CONDITIONS
 MIN

 I_{CEV}
 V_{CE}=Rated V_{CEO}, V_{BE}=1.5V
 MIN

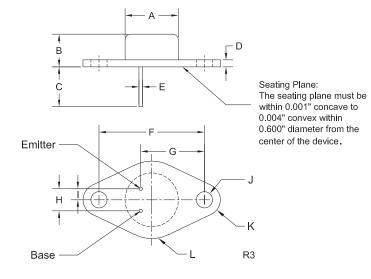
ICEV	V _{CE} =Rated V _{CEO} , V _{BE} =1.5V		0.5	mA
ICEV	V _{CE} =Rated V _{CEO} , V _{BE} =1.5V, T _C =150°C		5.0	mA
ICEO	V _{CE} =½Rated V _{CEO}		0.5	mA
IEBO	V _{EB} =5.0V		2.0	mA
BVCEO	I _C =100mA (2N6298, 2N6300)	60		V
BVCEO	I _C =100mA (2N6299, 2N6301)	80		V
V _{CE(SAT)}	I _C =4.0A, I _B =16mA		2.0	V
V _{CE} (SAT)	I _C =8.0A, I _B =80mA		3.0	V
V _{BE(SAT)}	I _C =8.0A, I _B =80mA		4.0	V
V _{BE(ON)}	V _{CE} =3.0V, I _C =4.0A		2.8	V
hFE	V _{CE} =3.0V, I _C =4.0A	750	18K	
h _{FE}	V _{CE} =3.0V, I _C =8.0A	100		
h _{fe}	V _{CE} =3.0V, I _C =3.0A, f=1.0kHz	300		
f _T	V _{CE} =3.0V, I _C =3.0A, f=1.0MHz	4.0		MHz
Cob	V _{CB} =10V, I _E =0, f=100kHz (NPN types)		200	pF
Cob	V _{CB} =10V, I _E =0, f=100kHz (PNP types)		300	pF

R3 (2-September 2014)



COMPLEMENTARY SILICON DARLINGTON POWER TRANSISTORS

TO-66 CASE - MECHANICAL OUTLINE



DIMENSIONS							
	INCHES		MILLIMETERS				
SYMBOL	MIN	MAX	MIN	MAX			
A (DIA)	0.470	0.500	11.94	12.70			
В	0.250	0.340	6.35	8.64			
С	0.360	-	9.14	-			
D	0.050	0.075	1.27	1.91			
E (DIA)	0.028	0.034	0.71	0.86			
F	0.956	0.964	24.28	24.48			
G	0.570	0.590	14.48	14.99			
Н	0.190	0.210	4.83	5.33			
ļ	0.093	0.107	2.36	2.72			
J (DIA)	0.142	0.152	3.61	3.86			
K (RAD)	0.141		3.58				
L (RAD)	0.345		8.76				
TO-66 (REV:R3)							

MARKING: FULL PART NUMBER

R3 (2-September 2014)

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OUTSTANDING SUPPORT AND SUPERIOR SERVICES

PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free guick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- · Environmental regulation compliance
- Customer specific screening
- · Up-screening capabilities

· Custom product packing

Custom bar coding for shipments

- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits
- · Custom product and package development

REQUESTING PRODUCT PLATING

- If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when 1. ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix " PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

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